TOSHIBA PHOTOCOUPLER IRED & PHOTO-IC

TLP2095

Programmable controllers Microprocessor system interfaces

The Toshiba TLP2095 consists of two infrared emitting diodes optically coupled to a high-gain, high-speed photodetector.

The TLP2095 is housed in a 6-pin MFSOP.

With a totem-pole output, the TLP2095 is capable of both sinking and sourcing current.

The TLP2095 has an internal Faraday shield, which provides a guaranteed/ common-mode transient immunity of ±10 kV/µs.

The TLP2095 has a noninverting output. An inverting-output version, the TLP2098, is also available.

- Buffer logic type (totem-pole output)
- Guaranteed Performance Over Temperature: -40 to 100°C
- Power Supply Voltage: 3.0 to 20 V
- Input Threshold Current: IFLH =±3 mA (max)
- Switching Time (tpLH/tpHL): 250 ns (max)
- Common mode transient immunity: ±15 kV/µs-
- Isolation Voltage: 3750 Vrms
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

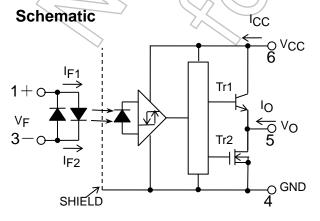
VDE-approved : EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed,

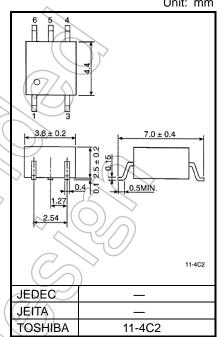
please designate the Option(V4).

Truth Table

				_
Input	LED) j ‡	Tr2	Output
ΛH	ON	ON	OFF	H/
7	OFF	OFF	ON	7

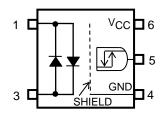


Unit: mm



Weight: 0.09 g (typ.)

Pin Configuration (top view)



- 1: Anode Cathode
- 3: Cathode Anode
- 4 : GND
- 5: Output
- 6: Vcc

0.1 μF bypass capacitor must be connected between pin 6 and 4

> Start of commercial production 2009-05

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Input Current, ON	I _{F(ON)}	5	_	15	mA
Input Voltage, OFF	V _F (OFF)	0	_	0.8	V
Supply Voltage*	VCC	3.0	_	20	V <
Operating Temperature	T _{opr}	-40	_	100	°C

^{*} This item denotes operating range, not meaning of recommended operating conditions.

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Absolute Maximum Ratings (Ta = 25°C)

	CHARACTERISTIC	SYMBOL (RATING	UNIT
	Forward Current	_F	±20	mĄ
	Forward Current Derating (Ta ≥ 83 °C)	ΔΙ _Ε /ΔΤα	-0.48	mA/°C
LED	Peak Transient Forward Current (Note 1)	FPT	<i>→</i> ±1	A
	Input Power Dissipation	PD	40	mW
	Input power dissipation derating (Ta ≥ 83 °C)	ΔΡ _D /ΔΤα	-0.96	mW/°C
	Output Current 1 (Ta ≤ 25 °C)	¹ 01	25/-15	mA
ᄶ	Output Current 2 (Ta ≤ 100 °C)	l _{O2}	5/-5	mA
DETECTOR	Output Voltage	> v _o //	-0.5 to 20	V
ETE	Supply Voltage	Vcc	-0.5 to 20	V
D	Output Power Dissipation	Po	7,5	mW
	Output Power Dissipation Derating (Ta ≥ 25°C)	ΔΡο /ΔΤα	-0.75	mW/°C
Opera	ating Temperature Range	Topr	-40 to 100	°C
Stora	ge Temperature Range	T _{stg}	-55 to 125	°C
Lead	Solder Temperature (10 s)	T _{SOI}	260	°C
Isolat	ion Voltage (AC, 60 s, R,H.≤ 60 %) (Note 2)	BVs	3750	V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Pulse width $\leq 1 \mu s$, 300 pps.

Note 2: Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

Electrical Characteristics

(Unless otherwise specified, Ta = -40 to 100° C, VCC = 3.0 to 20 V)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	COND	DITION	MIN	TYP.	MAX	UNIT
Input Forward Voltage	٧F	_	I _F = 10 mA , Ta =	= 25 °C	1.45	1.57	1.75	V
Temperature Coefficient of Forward Voltage	ΔV _F /ΔΤα	_	I _F = 10 mA		-	-2.0		mV/°C
Input Capacitance	CT	_	V = 0 V, f = 1 MH	Hz , Ta = 25 °C	-((190	-	pF
Logic Low Output Voltage	VOL	1	I _{OL} = 0.02 mA, \	V _F = 0.8 V		0.2	0.6	V
	.,	_	I _{OH} = -0.02 mA	V _{CC} = 3.0 V	2.0	2.5	_	.,
Logic High Output Voltage	VOH	2	$I_F = 5 \text{ mA}$	V _{CC} = 20 V	17.4	19.5	_	V
Logic Low Supply Current	ICCL	3	V _F = 0 V			- (3.0	mA
Logic High Supply Current	Іссн	4	IF = 5 mA		> -	7	3.0	mA
Logic Low Short Circuit Output Current (Note 3)	losL	5	V _F = 0 V	CC = VO = 4.5 V CC = VO = 20 V	15 20	80	-	mA
Logic High Short Circuit Output Current (Note 3)	losh	6		CC = 4.5 V	-5 -10	-12	// _ _	mA
Input Current Logic High Output	I _{FLH}	_	$I_0 = -0.02 \text{ mA}, V$	/ _O > 2.4 V	7/4	1.0	3.0	mA
Input Voltage Logic Low Output	VFHL	- <	I _O = 0.02 mA, V	O< 0.6 V	0.8	_	_	V
Input Current Hysteresis	I _{HYS}		V _{CC} = 5 V) —	0.05	_	mA

^{*}All typical values are at VCC = 5 V, Ta = 25 °C

Note 3: Duration of output short circuit time should not exceed 10 ms.

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition		MIN	TYP.	MAX	Unit
Capacitance input to output	CS	V _S = 0 V, f = 1 MHz	(Note 2)	-	8.0	-	pF
Isolation resistance	RS	R.H. ≤ 60 %,V _S = 500 V	(Note 2)	1×10 ¹²	10 ¹⁴		Ω
Isolation voltage	BVS	AC, 60 s	(Note 2)	3750	_		V _{rms}

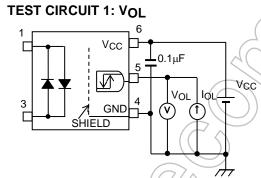
Switching Characteristics

(Unless otherwise specified, Ta = -40 to 100°C, VCC = 3.0 to 20 V)

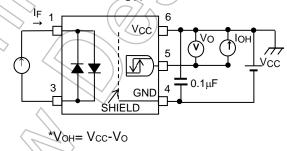
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	CONDITION	MIN	TYP.	MAX	UNIT
Propagation Delay Time to Logic High output	^t pLH		I _F = 0→5 mA	30	150	250	ns
Propagation Delay Time to Logic Low output	^t pHL	7, 8	I _F = 5→0 mA	30 (150	250	ns
Switching Time Dispersion between ON and OFF	t _{pHL} -t _{pLH}	(Note 4)	-			220	ns
Rise Time (10 – 90 %)	t _r		$I_F = 0 \rightarrow 5 \text{ mA}, V_{CC} = 5 \text{ V}$		30	75	ns
Fall Time (90 – 10 %)	t _f		$I_F = 5 \rightarrow 0 \text{ mA}, V_{CC} = 5 \text{ V}$	P	30	75	ns
Common Mode transient Immunity at High Level Output	СМ _Н		$V_{CM} = 1000 V_{p-p}, I_F = 5 \text{ mA},$ $V_{CC} = 20 \text{ V}, \text{ Ta} = 25 ^{\circ}\text{C}$	-15	- <		kV/μs
Common Mode transient Immunity at Low Level Output	CML	9	$V_{CM} = 1000 V_{p-p}, I_F = 0 \text{ mA},$ $V_{CC} = 20 \text{ V}, \text{ Ta} = 25 ^{\circ}\text{C}$	15) //>(kV/μs

^{*}All typical values are at Ta = 25 °C

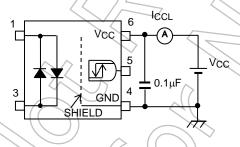
Note 4: Vcc = 4.5 to 20 V at test circuit 7.



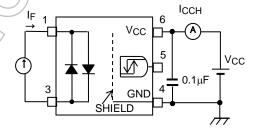




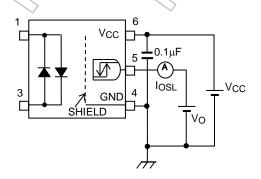
TEST CIRCUIT 3: ICCL



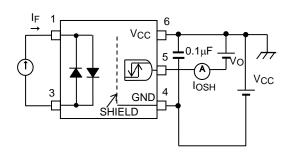
TEST CIRCUIT 4: ICCH



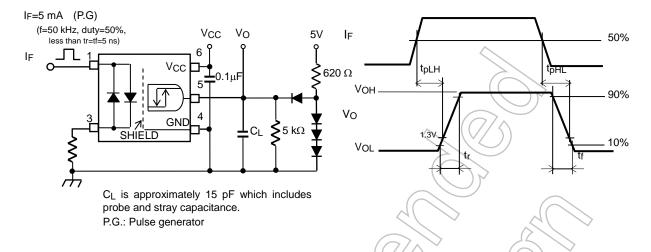
TEST CIRCUIT 5: IOSL



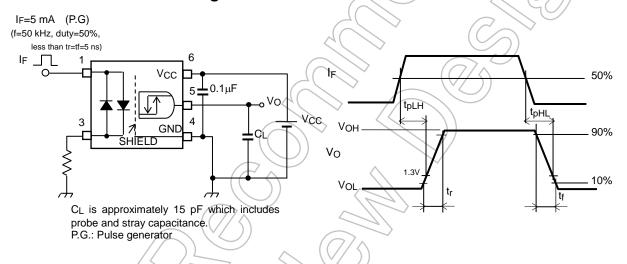
TEST CIRCUIT 6: IOSH



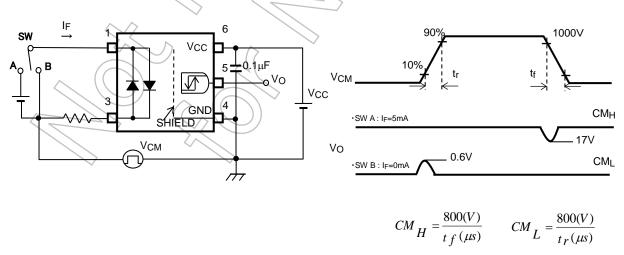
TEST CIRCUIT 7: Switching Time Test Circuit



TEST CIRCUIT 8: Switching Time Test Circuit



TEST CIRCUIT 9: Common Mode Transient Immunity Test Circuit



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Soldering and Storage

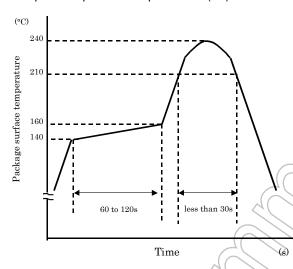
1. Soldering

1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

1) Using solder reflow

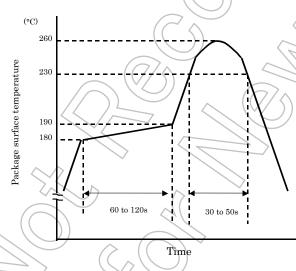
·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

(s)

- 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)
 - Please preheat it at 150°C between 60 and 120 seconds.
 - · Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.
- 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75% respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



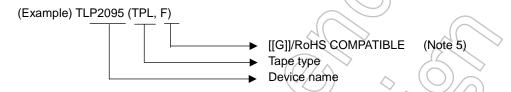
Specification for Embossed-Tape Packing (TPL)(TPR) for Mini-flat Coupler

1. Applicable Package

Package	Product Type
MFSOP	Mini-flat coupler

2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.



3. Tape Dimensions

3.1 Specification Classification are as shown in Table 1

Table 1 Tape Type Classification

Tape type	Classification	Quantity (pcs / reel)
TPL	L direction	3000
TPR	R direction	3000

3.2 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 1.

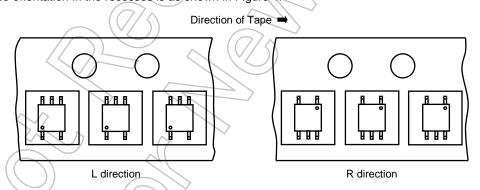


Figure 1 Device Orientation

3.3 Empty Device Recesses are as shown in Table 2.

Table 2 Empty Device Recesses

	Standard	Remarks
Occurrences of 2 or more successive empty device recesses	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty device recesses	6 devices (max) per reel	Not including leader and trailer

3.4 Start and End of Tape

The start of the tape has 50 or more empty holes. The end of tape has 50 or more empty holes and two empty turns only for a cover tape.

3.5 Tape Specification

- (1) Tape material: Plastic (protection against electrostatics)
- (2) Dimensions: The tape dimensions are as shown in Figure 2 and Table 3.

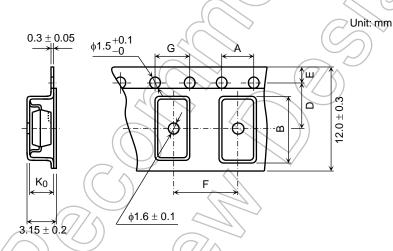


Figure 2 Tape Forms

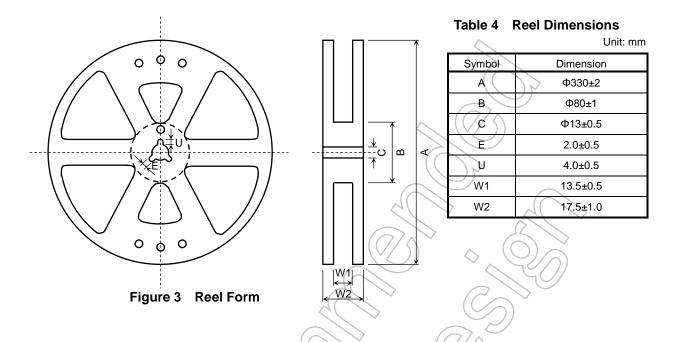
Table 3 Tape Dimensions

Unit: mm Unless otherwise specified: ±0.1

			0::::000 0:::000 0p00:::001 =0::
	Symbol	Dimension	Remark
J	Α _	4.2	-
	В((7.6	_
	D	5.5	Centre line of indented square hole and sprocket hole
	E	1.75	Distance between tape edge and hole center
	F	8.0	Cumulative error $^{+0.1}_{-0.3}$ (max) per 10 feed holes
	G	4.0	Cumulative error $^{+0.1}_{-0.3}$ (max) per 10 feed holes
	K ₀	2.8	Internal space

3.6 Reel

- (1) Material: Plastic
- (2) Dimensions: The reel dimensions are as shown in Figure 3 and Table 4.



4. Packing

Packed in a shipping carton.

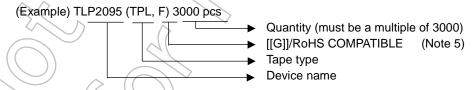
5. Label Indication

The carton bears a label indicating the product number, the symbol representing classification of standard, the quantity, the lot number and the Toshiba company name.

6. Ordering Method

When placing an order, please specify the product number, the tape type and the quantity as shown in the following example.

(Example)



Note 5 : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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